

SN55113, SN75113 DUAL DIFFERENTIAL LINE DRIVERS

SLLS070C – SEPTEMBER 1973 – REVISED MARCH 1997

- Choice of Open-Collector, Open-Emitter, or 3-State Outputs
- High-Impedance Output State for Party-Line Applications
- Single-Ended or Differential AND/NAND Outputs
- Single 5-V Supply
- Dual Channel Operation
- Compatible With TTL
- Short-Circuit Protection
- High-Current Outputs
- Common and Individual Output Controls
- Clamp Diodes at Inputs and Outputs
- Easily Adaptable to SN55114 and SN75114 Applications
- Designed for Use With SN55115 and SN75115

description

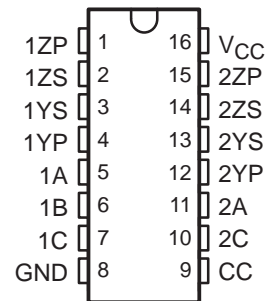
The SN55113 and SN75113 dual differential line drivers with 3-state outputs are designed to provide all the features of the SN55114 and SN75114 line drivers with the added feature of driver output controls. Individual controls are provided for each output pair, as well as a common control for both output pairs. If any output

is low, the associated output is in a high-impedance state and the output can neither drive nor load the bus. This permits many devices to be connected together on the same transmission line for party-line applications.

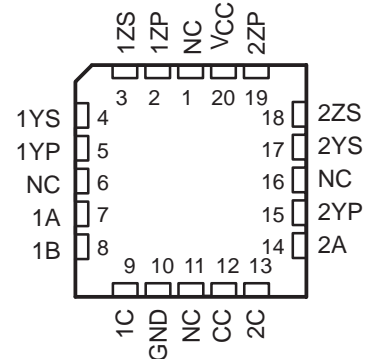
The output stages are similar to TTL totem-pole outputs, but with the sink outputs, YS and ZS, and the corresponding active pullup terminals, YP and ZP, available on adjacent package pins.

The SN55113 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN75113 is characterized for operation over the temperature range of 0°C to 70°C .

SN55113 . . . J OR W PACKAGE
SN75113 . . . N PACKAGE
(TOP VIEW)



SN55113 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

 **TEXAS
INSTRUMENTS**

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FUNCTION TABLE

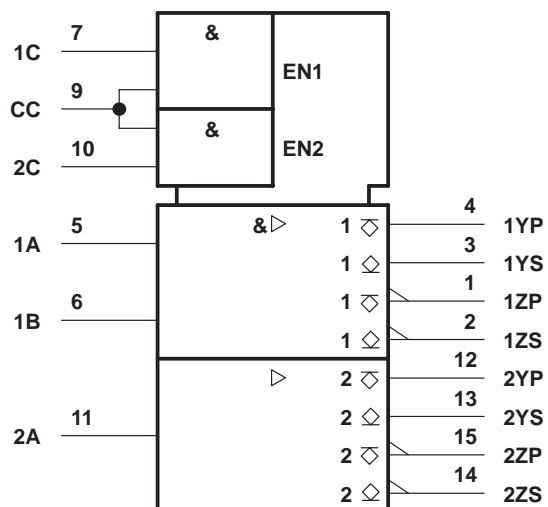
INPUTS		OUTPUTS			
OUTPUT C	CONTROL CC	DATA		AND Y	NAND Z
		A	B†		
L	X	X	X	Z	Z
X	L	X	X	Z	Z
H	H	L	X	L	H
H	H	X	L	L	H
H	H	H	H	H	L

H = high level, L = low level, X = irrelevant,

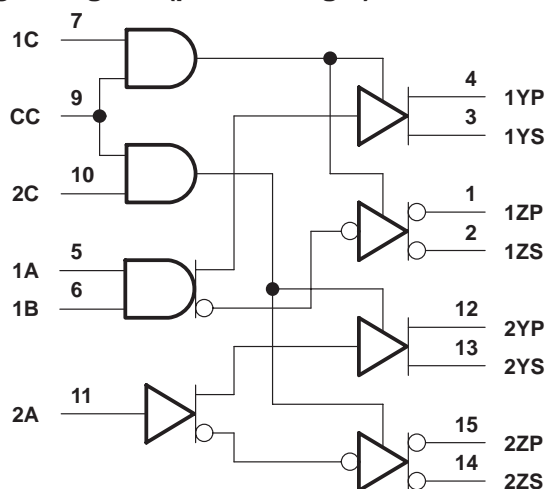
Z = high impedance (off)

† B input and 4th line of function table are applicable only to driver number 1.

logic symbol†



logic diagram (positive logic)



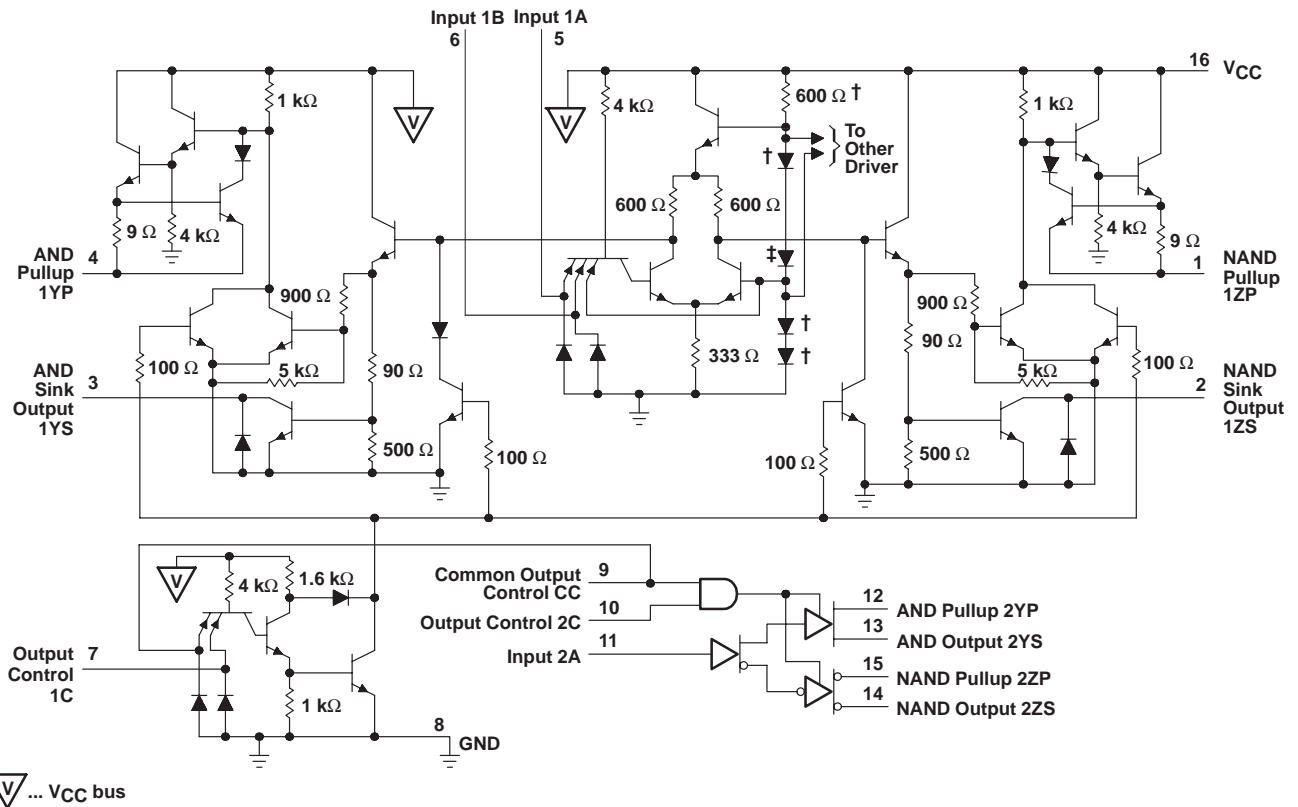
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the J, N, and W packages.

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schematic



† These components are common to both drivers. Resistor values shown are nominal and in ohms.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, V_{CC} (see Note 1)	7 V
Input voltage, V_I	5.5 V
Off-state voltage applied to open-collector outputs	12 V
Continuous total power dissipation (see Note 2)	See Dissipation Rating Table
Operating free-air temperature range, T_A : SN55113	-55°C to 125°C
SN75113	0°C to 70°C
Storage temperature range, T_{Stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: N package	260°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W package	300°C

‡ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	N/A
W	1000 mW	8.0 mW/°C	640 mW	200 mW

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recommended operating conditions

	SN55113			SN75113			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V_{IH}	2			2			V
Low-level input voltage, V_{IL}	0.8			0.8			V
High-level output current, I_{OH}	-40			-40			mA
Low-level output current, I_{OL}	40			40			mA
Operating free-air temperature, T_A	-55			125			°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		SN55113			SN75113			UNIT	
				MIN	TYP‡	MAX	MIN	TYP‡	MAX		
V_{IK}	Input clamp voltage	$V_{CC} = \text{MIN}$, $I_I = -12 \text{ mA}$		-0.9		-1.5	-0.9		-1.5	V	
V_{OH}	High-level output voltage	$V_{CC} = \text{MIN}$, $V_{IL} = 0.8 \text{ V}$	$V_{IH} = 2 \text{ V}$, $I_{OH} = -10 \text{ mA}$	2.4	3.4		2.4	3.4		V	
				2	3.0		2	3.0			
V_{OL}	Low-level output voltage	$V_{CC} = \text{MIN}$, $I_{OL} = 40 \text{ mA}$	$V_{IH} = 2 \text{ V}$, $V_{IL} = 0.8 \text{ V}$,	0.23		0.4	0.23		0.4	V	
V_{OK}	Output clamp voltage	$V_{CC} = \text{MAX}$, $I_O = -40 \text{ mA}$		-1.1		-1.5	-1.1		-1.5	V	
$I_{O(\text{off})}$	Off-state open-collector output current	$V_{CC} = \text{MAX}$	$V_{OH} = 12 \text{ V}$	$T_A = 25^\circ\text{C}$	1	10				μA	
				$T_A = 125^\circ\text{C}$			200				
			$V_{OH} = 5.25 \text{ V}$	$T_A = 25^\circ\text{C}$				1	10		
				$T_A = 70^\circ\text{C}$					20		
I_{OZ}	Off-state (high-impedance-state) output current	$V_{CC} = \text{MAX}$, Output controls at 0.8 V	$T_A = \text{MAX}$	$T_A = 25^\circ\text{C}$, $V_O = 0 \text{ to } V_{CC}$		± 10			± 10	μA	
				$V_O = 0$		-150			-20		
				$V_O = 0.4 \text{ V}$		± 80			± 20		
				$V_O = 2.4 \text{ V}$		± 80			± 20		
				$V_O = V_{CC}$		80			20		
I_I	Input current at maximum input voltage	A, B, C	$V_{CC} = \text{MAX}$, $V_I = 5.5 \text{ V}$			1			1	mA	
		CC				2			2		
I_{IH}	High-level input current	A, B, C	$V_{CC} = \text{MAX}$, $V_I = 2.4 \text{ V}$			40			40	μA	
		CC				80			80		
I_{IL}	Low-level input current	A, B, C	$V_{CC} = \text{MAX}$, $V_I = 0.4 \text{ V}$			-1.6			-1.6	mA	
		CC				-3.2			-3.2		
I_{OS}	Short-circuit output current§	$V_{CC} = \text{MAX}$, $V_O = 0$, $T_A = 25^\circ\text{C}$		-40	-90	-120	-40	-90	-120	mA	
I_{CC}	Supply current (both drivers)	All inputs at 0 V, No load, $T_A = 25^\circ\text{C}$		$V_{CC} = \text{MAX}$			$V_{CC} = 7 \text{ V}$			mA	
				47	65		47	65			
				65	85		65	85			

† All parameters with the exception of off-state open-collector output current are measured with the active pullup connected to the sink output. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at $T_A = 25^\circ\text{C}$ and $V_{CC} = 5 \text{ V}$, with the exception of V_{CC} at 7 V.

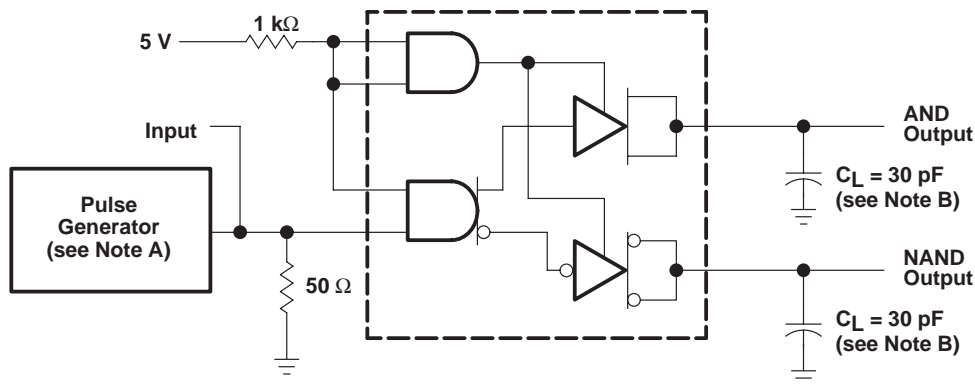
§ Only one output should be shorted at a time, and duration of the short-circuit should not exceed one second.



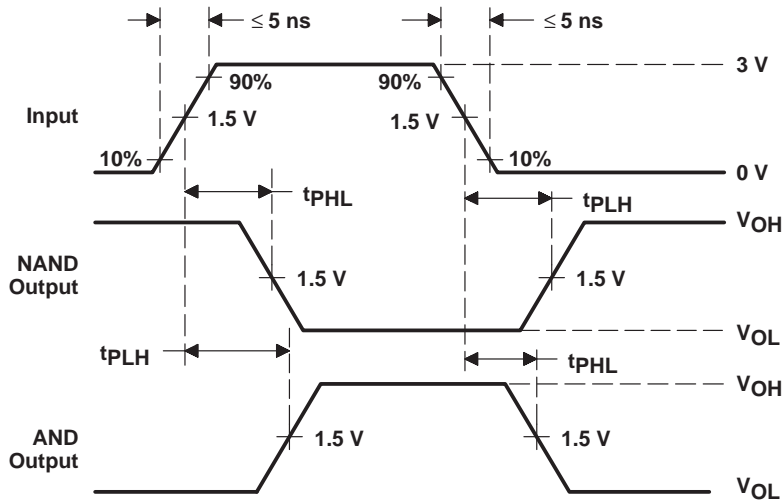
switching characteristics, $V_{CC} = 5\text{ V}$, $C_L = 30\text{ pF}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	SN55113			SN75113			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
t_{PLH} Propagation delay time, low-to-high level output	See Figure 1		13	20		13	30	ns
t_{PHL} Propagation delay time, high-to-low-level output			12	20		12	30	
t_{PZH} Output enable time to high level	$R_L = 180\ \Omega$, See Figure 2		7	15		7	20	ns
t_{PZL} Output enable time to low level	$R_L = 250\ \Omega$, See Figure 3		14	30		14	40	ns
t_{PHZ} Output disable time from high level	$R_L = 180\ \Omega$, See Figure 2		10	20		10	30	ns
t_{PLZ} Output disable time from low level	$R_L = 250\ \Omega$, See Figure 3		17	35		17	35	ns

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



VOLTAGE WAVEFORMS

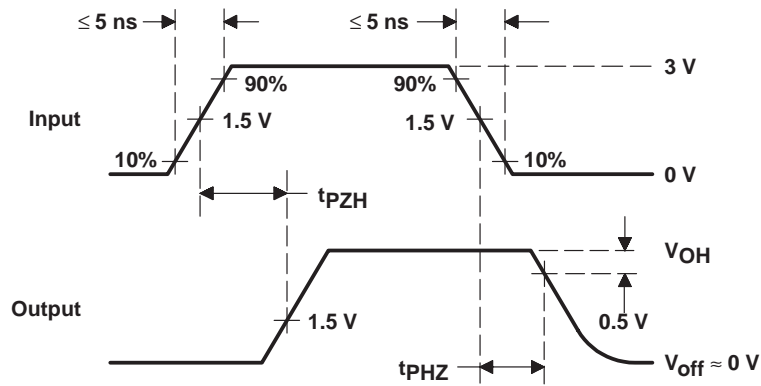
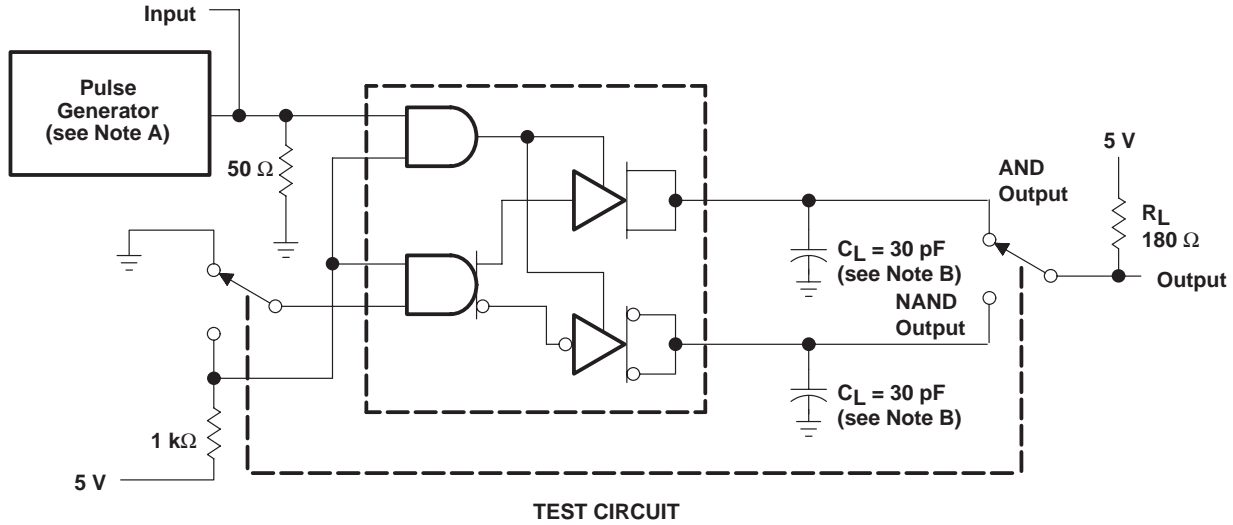
- NOTES: A. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, $PRR \le 500\text{ kHz}$, $t_w = 100\text{ ns}$.
B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms t_{PLH} and t_{PHL}

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PARAMETER MEASUREMENT INFORMATION

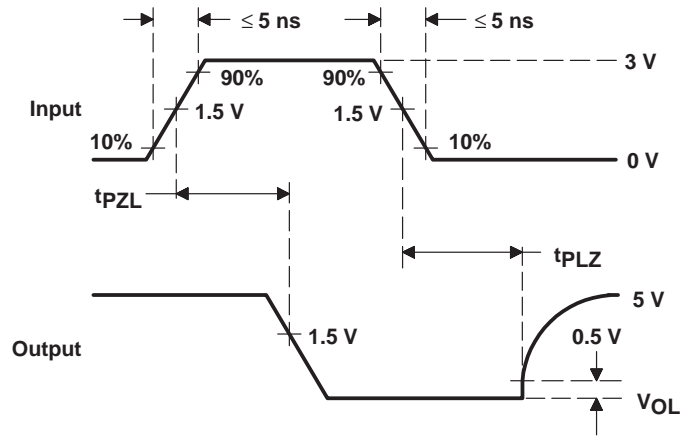
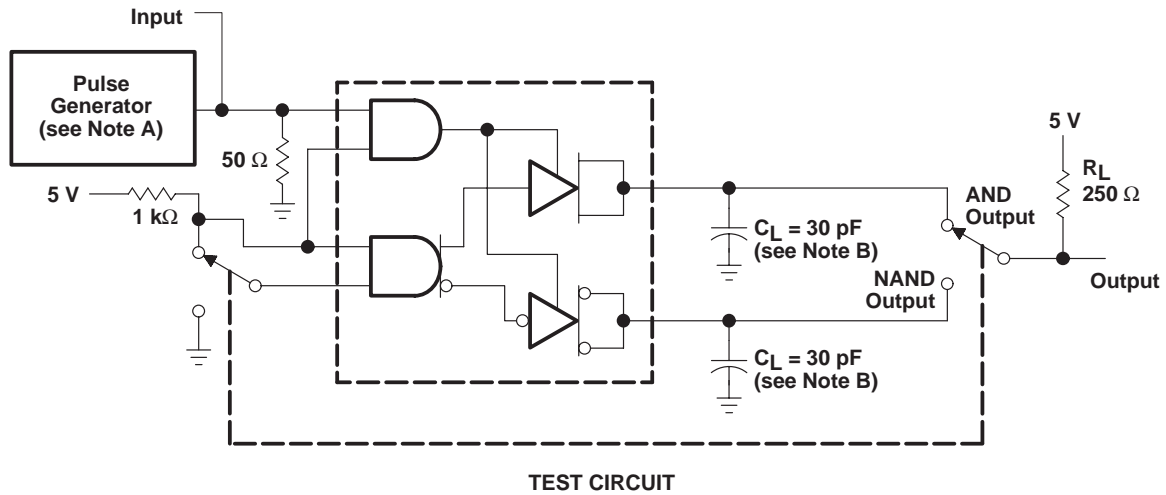


VOLTAGE WAVEFORMS

- NOTES: A. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, $PRR \leq 500\text{ kHz}$, $t_w = 100\text{ ns}$.
B. C_L includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms t_{pZH} and t_{pHZ}

PARAMETER MEASUREMENT INFORMATION



VOLTAGE WAVEFORMS

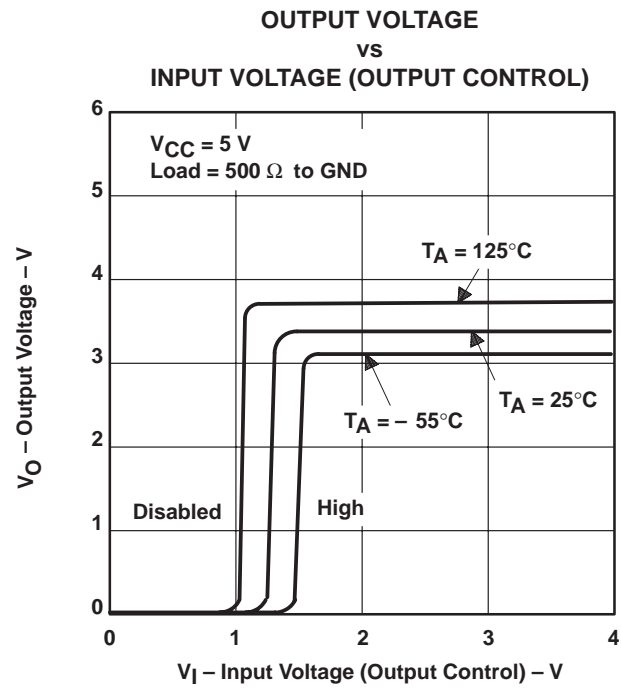
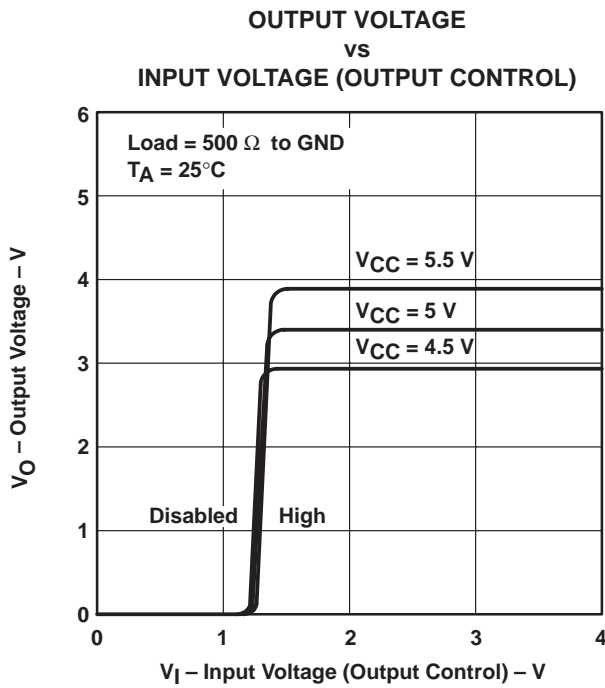
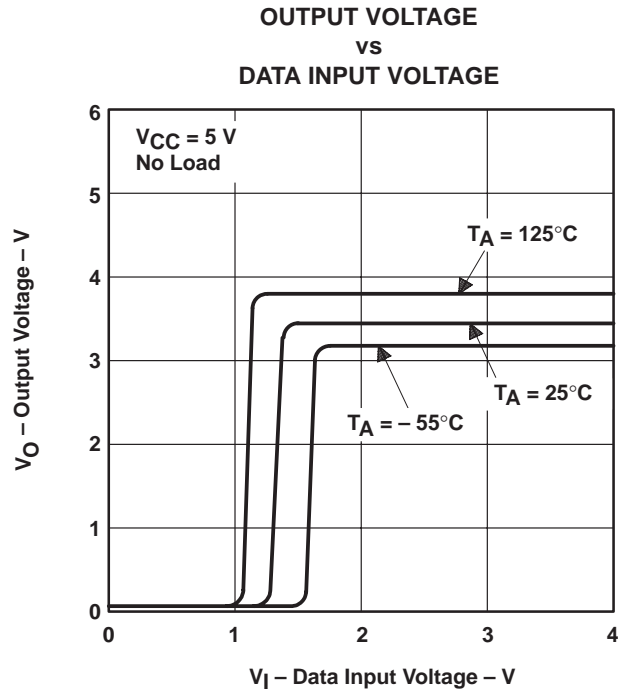
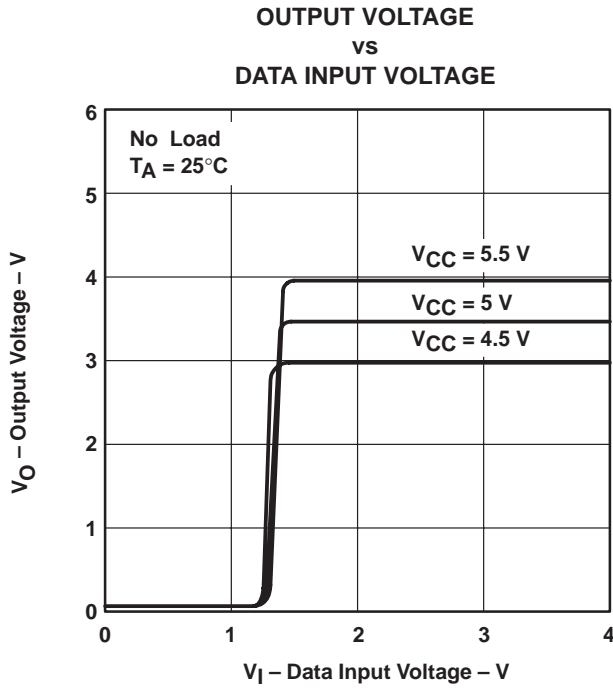
- NOTES: A. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, $PRR \leq 500$ kHz, $t_W = 100$ ns.
 B. C_L includes probe and jig capacitance.

Figure 3. Test Circuit and Voltage Waveforms, t_{PZL} and t_{PLZ}

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TYPICAL CHARACTERISTICS†



† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.

TYPICAL CHARACTERISTICS†

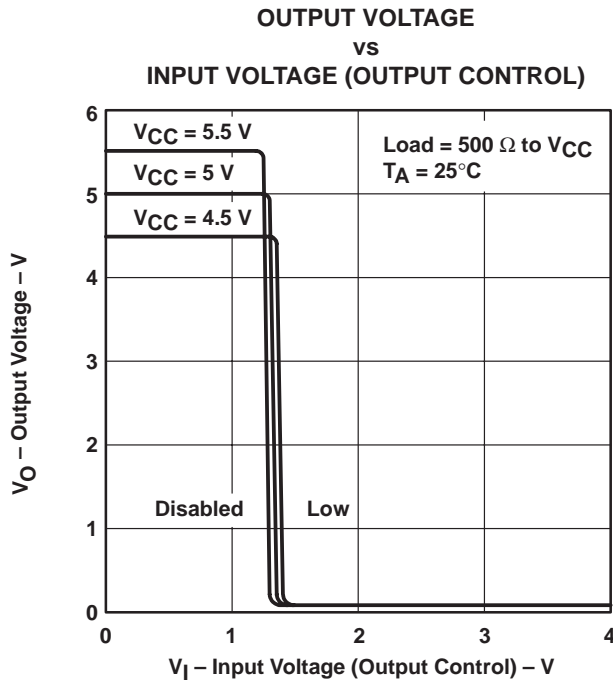


Figure 8

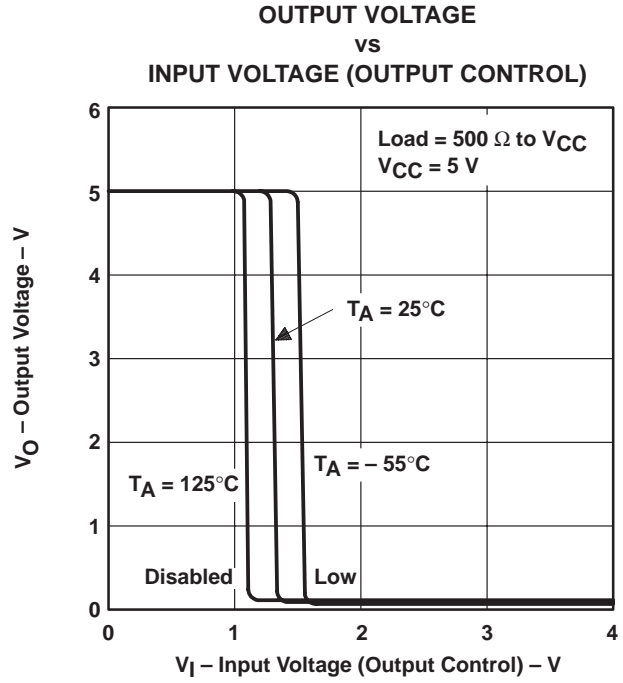


Figure 9

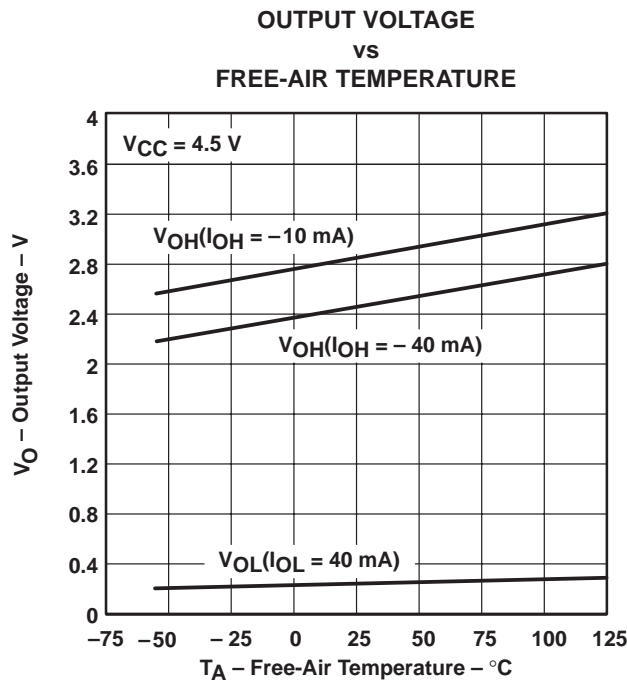


Figure 10

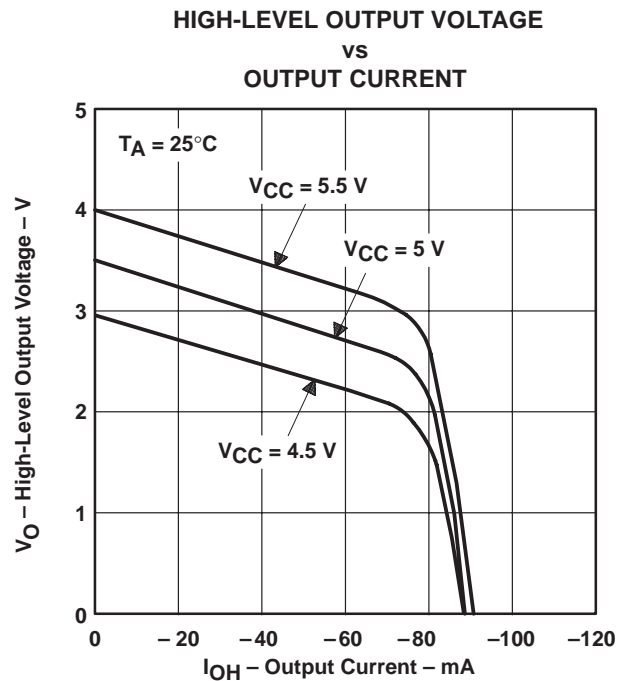


Figure 11

† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.

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TYPICAL CHARACTERISTICS†

LOW-LEVEL OUTPUT VOLTAGE
vs
OUTPUT CURRENT

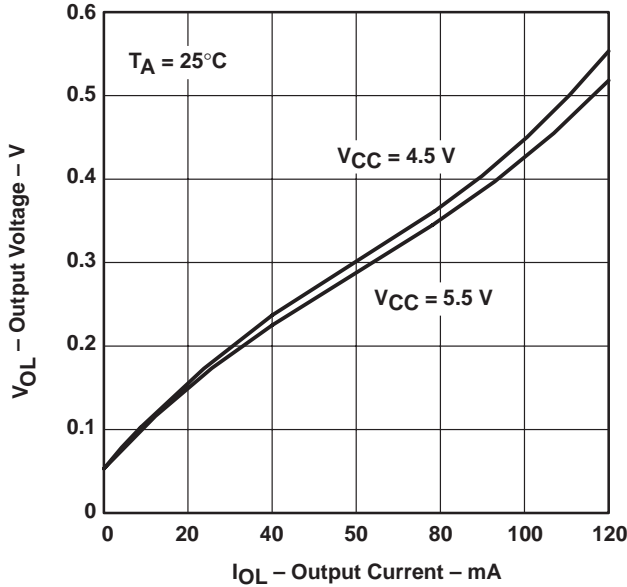


Figure 12

SUPPLY CURRENT
(BOTH DRIVERS)
vs
SUPPLY VOLTAGE

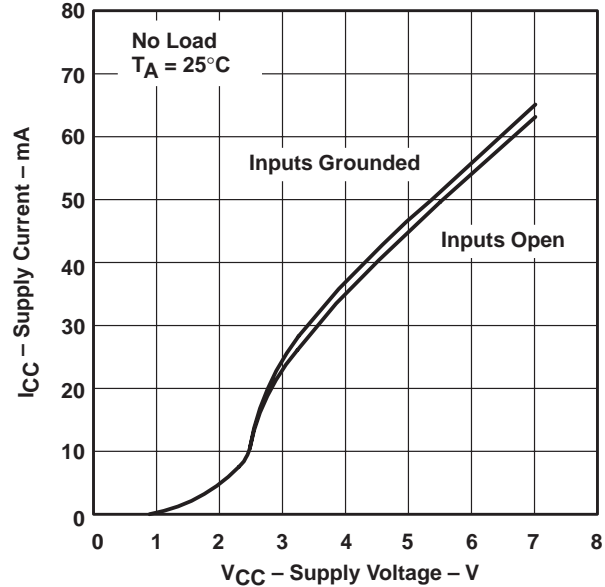


Figure 13

SUPPLY CURRENT
(BOTH DRIVERS)
vs
OUTPUT CURRENT

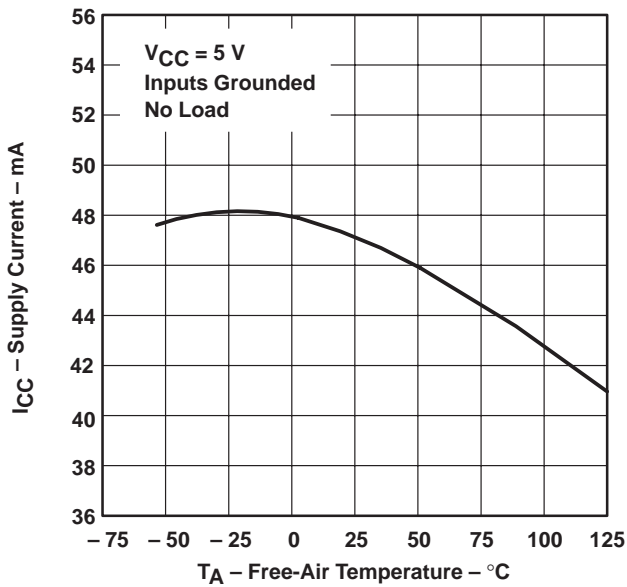


Figure 14

SUPPLY CURRENT
(BOTH DRIVERS)
vs
SUPPLY VOLTAGE

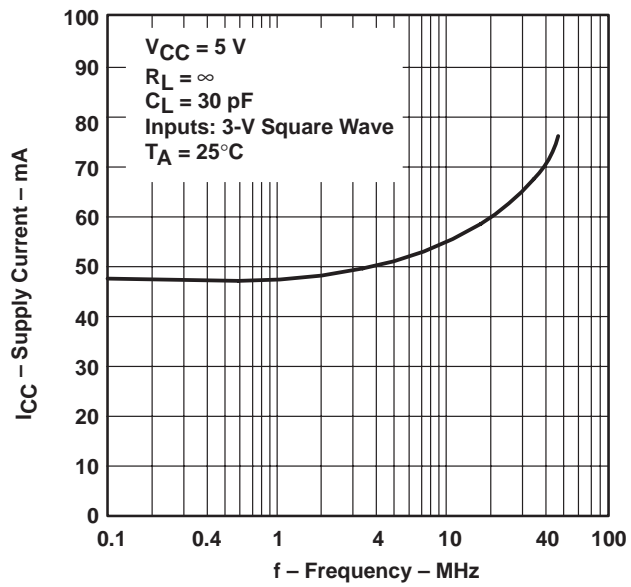
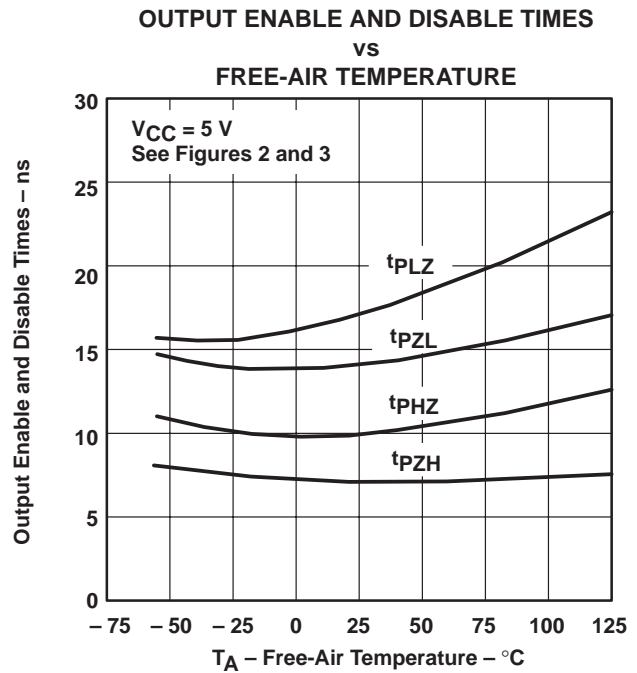
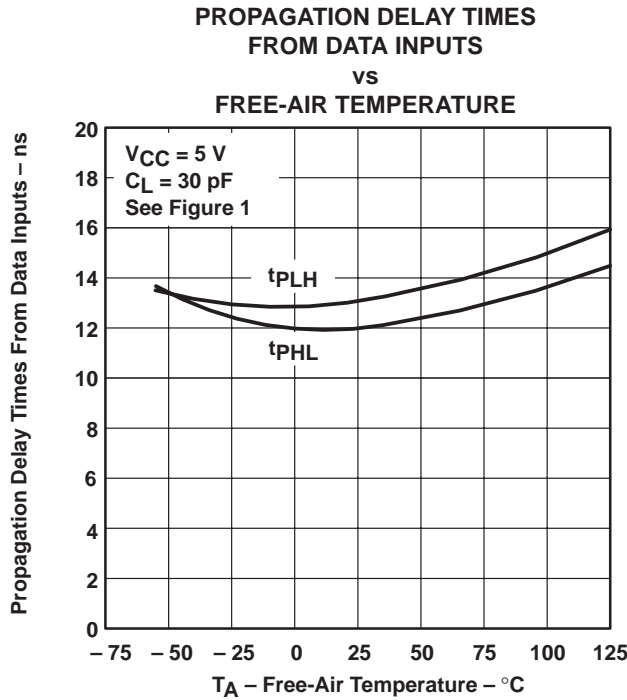


Figure 15

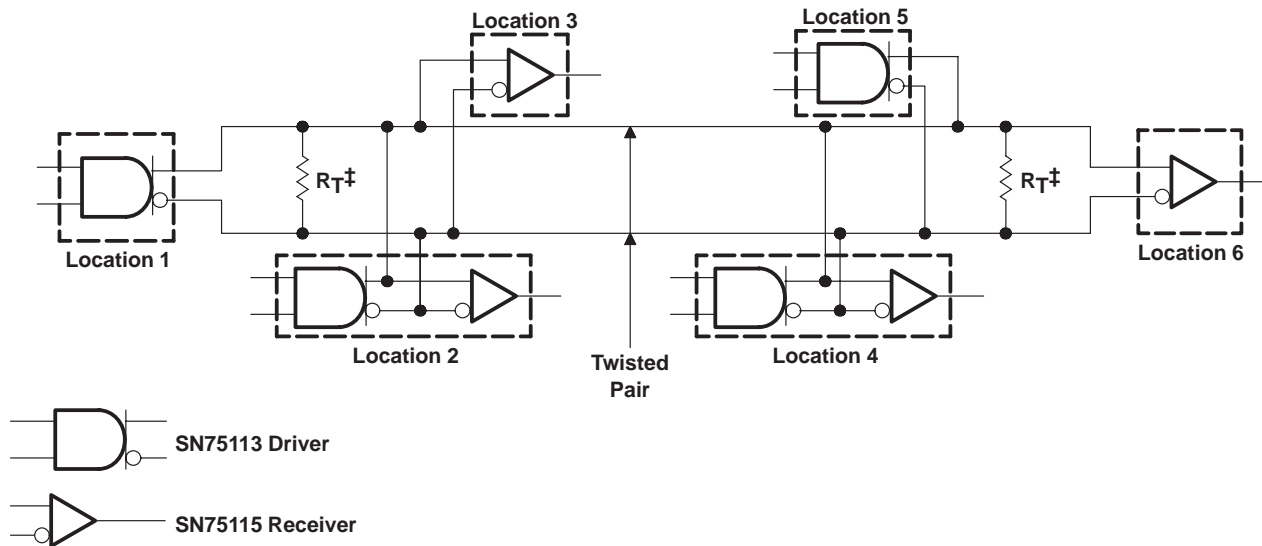
† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.

TYPICAL CHARACTERISTICS†



† Data for temperatures below 0°C and above 70°C and for supply voltages below 4.75 V and above 5.25 V are applicable to SN55113 circuits only. These parameters were measured with the active pullup connected to the sink output.

APPLICATION INFORMATION



† $R_T = Z_O$. A capacitor may be connected in series with R_T to reduce power dissipation.

Figure 18. Basic Party-Line or Data-Bus Differential Data Transmission

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